

PATENT

Docket No.: CPH35726-D1

#2/A
5/13/02
Moulin

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: KUAN-YU FU et al.)
Filed: Herewith)
For: MOSFET DEVICE)

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

Prior to the examination on merits, please amend the above-identified application as follows:

IN THE TITLE:

✓
Please change the title to read:

--MOSFET DEVICE--

IN THE SPECIFICATION:

Please add the following paragraph on page 1, after line 2.

--CROSS-REFERENCE TO RELATED APPLICATION

A1 This application is a divisional application of, and claims the priority benefit of, U.S. application serial No. 09/382,146 filed on August 24, 1999, which in turn is a divisional application of U.S. Patent application No. 09/059,548, filed on April 13, 1998.--

IN THE CLAIMS:

✓
Please cancel claims 1-9 without prejudice and disclaimer.

Please add the following new claims 10-12:

10. A semiconductor structure comprising a substrate having an active region of a first conductivity type including a channel region and a non-channel region surrounding the channel